

## SAM<sup>TM</sup> Data Sheet SAM-980-4-1ps-x, $\lambda$ = 980 nm

Laser wavelength  $\lambda = 980 \text{ nm}$ 

High reflection band  $\lambda = 910 ... 990 \text{ nm}$ 

Saturable absorptance  $A_0$  = 4 % Modudation depth  $\Delta R$  = 2.4 % Non-saturable loss  $A_{ns}$  = 1.6 % Saturation fluence  $\Phi_{sat}$  = 80  $\mu$ J/cm<sup>2</sup>

Relaxation time constant  $\tau \sim 1 ps$ 

Damage threshold  $\Phi = 1.2 \text{ mJ/cm}^2$ 

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

x = 0 unmounted

 $x = 12.7 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$  $x = 25.4 \, \mathrm{g}$ glued on a gold plated Cu-cylinder with 25.4 mm  $\varnothing$  $x = 12.7 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 12.7 mm  $\varnothing$  $x = 25.4 \, \mathrm{s}$ soldered on a gold plated Cu-cylinder with 25.4 mm  $\varnothing$ x = FCmounted on a 1 m monomode fiber cable with FC connector

## Low intensity spectral reflectance

